

**ELECTRONIC INFORMATION DISCLOSURE STATEMENT**

Electronic Version v18

Stylesheet Version v18.0

**Title of Invention****ISOLATED FULLY DEPLETED SILICON-ON-INSULATOR REGIONS BY  
SELECTIVE ETCH**

Application Number:

Confirmation Number:

First Named Applicant: Matthew Breitwisch

Attorney Docket Number: BUR920040015US1

Search string: ( 5306659 or 5324683 or 5391911 or 6020250 or 6492705 ).pn.

**US Patent Documents****Note: Applicant is not required to submit a paper copy of cited US Patent Documents**

init	Cite.No.	Patent No.	Date	Patentee	Kind	Class	Subclass
	1	5306659	1994-04-26	Beyer et al			
	2	5324683	1994-06-08	Fitch et al			
	3	5391911	1995-02-21	Beyer et al			
	4	6020250	2000-02-01	Kenny			
	5	6492705	2002-12-10	Begley et al			

**Signature****Examiner Name****Date**